AD172A Datasheet

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AD172A Features

CPU

- 32bit DSP
- Maximum speed 160MHz
- Interrupts with 8 priority level

Memory

Optional built-in flash memory

Clocks

- On-chip 16 MHz clock
- On-chip 200KHz lower-temperature-drift clock

Audio APA

- Support for driving 4 or 8 ohm speaker
- Mono Class-D Speaker Amplifier
 - 0.42W/8 Ω @3.7V
 - $0.17W/8 \Omega @2.4V$
 - 0.62W/4 Ω @3.7V
 - 0.25W/4 Ω @2.4V

Peripherals

- Three multi-function 16-bit timers, support capture and PWM mode
- Two UART Controllers(UART0/1) supports DMA and Flow Control
- One IIC Master controller

- Two SPI Master / Slaver controller with DMA SPI0 support 4bit,SPI1 support 2bit
- A0:8-channel 10-bit general purpose ADC A2/4:10-channel 10-bit general purpose ADC
- 4-channel Advance PWM controller
- 13 Individually programmable and multiplexed GPIO pins
- Digital peripheral crossbar
- Up to 12 external interrupt / wake-up source (low power available,can be multiplexed to any I/O)
- Watchdog

PMI

- Less than 2uA soft off current
- VBAT range : 2.0V to 5.5V
- IOVDD range: 2.0V to 3.4V

Packages

SOP16

Temperature

- Operating temperature: -40° C to $+85^{\circ}$ C
- Storage temperature: -65° C to $+150^{\circ}$ C

Applications

- Sound Toy
- Audio player
- Universal Microcontroller



1 Block Diagram

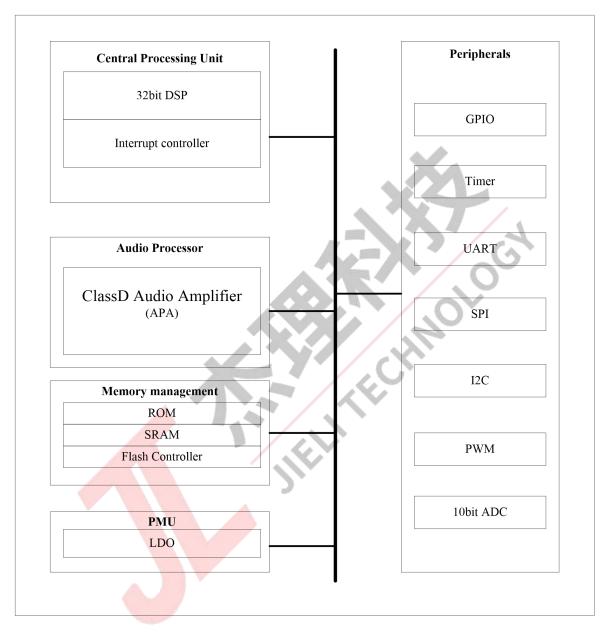


Figure 1-1 AD172A Block Diagram



2 Pin Definition

2.1 Pin Assignment

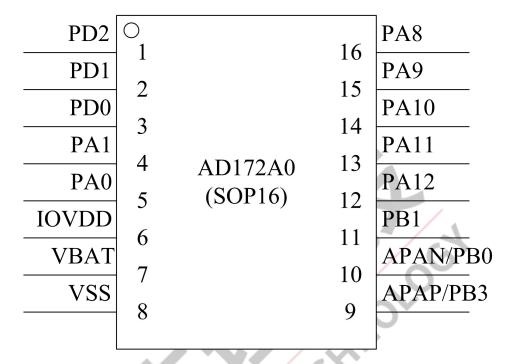


Figure 2-1 AD172A0 Package Diagram

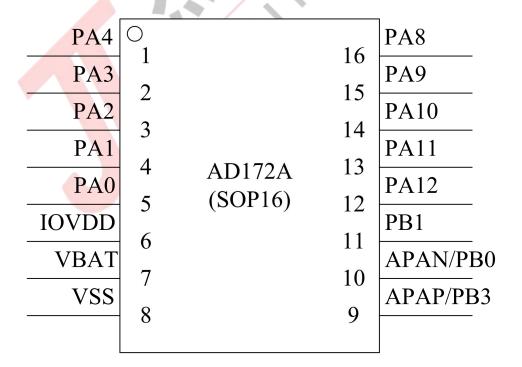


Figure 2-2 AD172A2/4 Package Diagram



2.2 Pin Description

Table 2-1 AD172A Pin Description

				Table 2-1 AD17	2A Pin Description		
PIN NO.	Na	ime	Туре	Function	Other Function		
	A0	PD2	I/O	GPIO	SFCCS:SFC Chip Select;		
					ADC4:ADC Input Channel 4;		
					PWMCK0;		
1	A2/4	PA4	I/O	GPIO	SPI0D3:SPI0 Data 3;		
					UART0RX:Uart0 Data Input;		
					PWMCH1H:Motor PWM Channel1(H);		
					SFCDO:SFC Data Out;		
	A0	PD1	I/O	GPIO	ADC13:ADC Input Channel 13;		
					ADC3:ADC Input Channel 3;		
					SPI0D2:SPI0 Data 2;		
2					UART0TX:Uart0 Data Output;		
	A2/4	PA3	I/O	GPIO	PWMCH1L:Motor PWM Channel1(L);		
					CAP0:Timer0 Capture;		
					CAP2:Timer2 Capture;		
					PWM0:Timer0 PWM Output;		
	A0	PD0	I/O	GPIO	SFCCLK:SFC Clk;		
					ADC2:ADC Input Channel 2;		
_					SPI0DI:SPI1 Data In;		
3	A2/4	PA2	I/O	GPIO	TMR0:Timer0 Clock Input;		
					TMR2:Timer2 Clock Input;		
					PWM2:Timer2 PWM Output;		
		13	1		ADC1:ADC Input Channel 1;		
	1		1 1 1 E		SPI0DO(0):SPI0 Data Out(0);		
4	PA1		I/O	GPIO	I2C SDA;		
4	FAI		1/0	GFIO	PWMCH0H:Motor PWM Channel0(H);		
							CAP1:Timer1 Capture;
			A)	11 12 12 12 12 12 12 12 12 12 12 12 12 1	LVD:Low Voltage Detect;		
			All the		Long press reset;		
					ADC0:ADC Input Channel 0;		
				GPIO	SPI0CLK:SPI0 Clk;		
5	PA0	PA0		(pull up)	I2C SCL;		
				(han ah)	TMR1:Timer1 Clock Input;		
					PWM1:Timer1 PWM Output;		
					PWMCH0L:Motor PWM Channel0(L);		
6	IOVD:	D	PO	Power supply for GPIO	Built-in linear voltage regulator output;		
7	VBAT		PI		Power supply input;		
8	VSS		G		System ground;		



9	APAP	О		Class-D APA Positive Output;
	PB3	I/O	5V tolerant IO	
10	APAN	0		Class-D APA Negative Output;
10	PB0	I/O	5V tolerant IO	
11	PB1	I/O	5V tolerant IO	Serial port code upgrade pin; APA_DOP;
12	PA12	I/O	GPIO	ADC12:ADC Input Channel 12; PWMFP1;
13	PA11	I/O	GPIO	ADC11:ADC Input Channel 11; PWMFP0;
14	PA10	I/O	GPIO	ADC10:ADC Input Channel 10;
15	PA9	I/O	GPIO (pull down)	ADC9:ADC Input Channel 9; Touch cap; CLK OUT2:Internal clock output2;
16	PA8	I/O	GPIO (pull down)	ADC8:ADC Input Channel 8; SPI1DI:SPI1 Data In; WKUP; CLK OUT1:Internal clock output1;

Pin Type	Description	Pin Type	Description
P	Power	I/O	Input or Output
PI	Power Input	I	Input
PO	Power Output	O	Output
AO	Analog Output	G	Ground



3 Electrical Characteristics

3.1 Absolute Maximum Ratings

Table 3-1

Symbol	Parameter	Min	Max	Unit
Topt	Operating temperature	-40	+85	°C
Tstg	Storage temperature	-65	+150	°C
VBAT	Supply Voltage	-0.3	6	V
$V_{\rm IOVDD}$	Voltage applied at IOVDD	-0.3	3.6	V
$ m V_{GPIO}$	Voltage applied to GPIO	-0.3	IOVDD+0.3	V
$ m V_{HVIO}$	Voltage applied to High Voltage Resistant IO	-0.3	+5.5	V

Note: The chip can be damaged by any stress in excess of the absolute maximum ratings listed below

3.2 PMU Characteristics

Table 3-2

Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
VBAT	Voltage Input	2.0	3.7	5.5	V	
IOVDD	Voltage output	2.0	3.0	3.4	V	VBAT = 4.2V, 10mA loading
10 ()	Loading current	4	<u> </u>	100	mA	IOVDD=3.3V@VBAT ≥ 3.6V
$V_{ m LVD}$	Voltage input	1.8	2.5	2.5	V	Low-Voltage Detection of IOVDD

3.3 IO Input/Output Electrical Logical Characteristics

Table 3-3

GPIO input ch	GPIO input characteristics									
Symbol	Parameter Min		Тур	Max	Unit	Test Conditions				
$ m V_{IL}$	Low-Level Input Voltage	-0.3	_	0.3* IOVDD	V	IOVDD = 3.0V				
$ m V_{IH}$	High-Level Input Voltage	0.7* IOVDD	_	IOVDD+0.3	V	IOVDD = 3.0V				
High Voltage R	esistant IO input chara	cteristics								
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions				
V _{IL}	Low-Level Input Voltage	-0.3	_	0.3* IOVDD	V	IOVDD = 3.0V				
V_{IH}	High-Level Input Voltage	0.7* IOVDD	_	+5V	V	IOVDD = 3.0V				
Resistant IO ou	itput characteristics									
Symbol	Paramete	er	GPIO	Тур	Unit	Test Conditions				
	0.1*IOVDD Driv	PA0~PA4 PA8~PA12	HD=1:-7 HD=2:-22 HD=3:-27		IOVDD = 3.0V					
$ m V_{OL}$			PB0,PB1 PB3	-7	mA					
	0.1*HPVDD Driv APA IO total current l		APAN APAP	-400		VBAT=3.7V				



$ m V_{OH}$	0.9*IOVDD Drive current	PA0~PA4 PA8~PA12	HD=1:7 HD=2:24 HD=3:56	mA	IOVDD = 3.0V	
		PB0,PB1 PB3	7			
	0.9*HPVDD Drive current APA IO total current limit of 400mA	APAN APAP	400		VBAT=3.7V	

3.4 Internal Resistor Characteristics

Table 3-4

Port	Internal Pull-Up Resistor	Internal Pull-Down Resistor	Comment
PA0~PA4,PA8~PA12 PB0,PB1,PB3	10K	200K	 PA0 default pull up PA8~PA9 default pull down Internal pull-up/pull-down resistance accuracy ±20%

3.5 Audio APA Characteristics

Table 3-5

Parameter	MODE	Min	Тур	Max	Unit	Test	Conditions
Frequency Response		20		20K	Hz	R _L =10K	,VBAT=3.7V
		10.M	1.57	/X	Vrms	$R_L=4\Omega$	
	Diff (N to P)		1.83	V	Vrms	$R_L=8\Omega$	f=1kHz/0dB
			2.22	_	Vrms	R _L =10K	VBAT=3.7V
Output Swing	Single-ended		1.11	_	Vrms	R _L =10K	
Output Swing		_	0.99	_	Vrms	$R_L=4\Omega$	
	Diff (N to P)	_	1.17	_	Vrms	$R_L=8\Omega$	f=1kHz/0dB
	1	_	1.44	_	Vrms	R _L =10K	VBAT=2.4V
	Single-ended	_	0.72	_	Vrms	R _L =10K	
			0.62	_	W	$R_L=4\Omega$	f=1kHz/0dB
Output power	Diff (N to P)		0.42	_	W	$R_L=8\Omega$	VBAT=3.7V
Output power			0.25	_	W	$R_L=4\Omega$	f=1kHz/0dB
		_	0.17	_	W	$R_L=8\Omega$	VBAT=2.4V
		_	-31	_	dB	$R_L=4\Omega$	f=1kHz/0dB
	Diff (N to P)	_	-35	_	dB	$R_L=8\Omega$	A-Weighted
		_	-75	_	dB	R _L =10K	VBAT=3.7V
THD+N	Single-ended	_	-70	_	dB	R _L =10K	VB/11 3.7 V
1112.11		_	-31	_	dB	$R_L=4\Omega$	f=1kHz/0dB
	Diff (N to P)	_	-36	_	dB	$R_L=8\Omega$	A-Weighted
		_	-73	_	dB	R _L =10K	VBAT=2.4V
	Single-ended	_	-70	_	dB	R _L =10K	, D/11 2. TV
		_	97	_	dB	$R_L=4\Omega$	f=1kHz/0dB
S/N	Diff (N to P)	_	97	_	dB	$R_L=8\Omega$	A-Weighted
		_	95	_	dB	R _L =10K	VBAT=3.7V



	Single-ended	-	75	_	dB	R _L =10K	
		_	94	_	dB	$R_L=4\Omega$	C-11-II-/0 ID
S/N	Diff (N to P)	_	94	_	dB	$R_L=8\Omega$	f=1kHz/0dB
		_	88	_	dB	R _L =10K	A-Weighted VBAT=2.4V
	Single-ended	_	72	_	dB	R _L =10K	VBA1=2.4 V
	Diff (N to P)	_	88	_	dB	$R_L=4\Omega$	f=1kHz/-60dB
		_	88	_	dB	$R_L=8\Omega$	
		_	86	_	dB	R _L =10K	A-Weighted
D ' D	Single-ended	_	75	_	dB	R _L =10K	VBAT=3.7V
Dynamic Range	Diff (N to P)	_	87	_	dB	$R_L=4\Omega$	C 11 II / CO 1D
		_	87	_	dB	$R_L=8\Omega$	f=1kHz/-60dB
		_	85	_	dB	R _L =10K	A-Weighted
	Single-ended	_	74		dB	R _L =10K	VBAT=2.4V



4 Package Information

4.1 SOP16

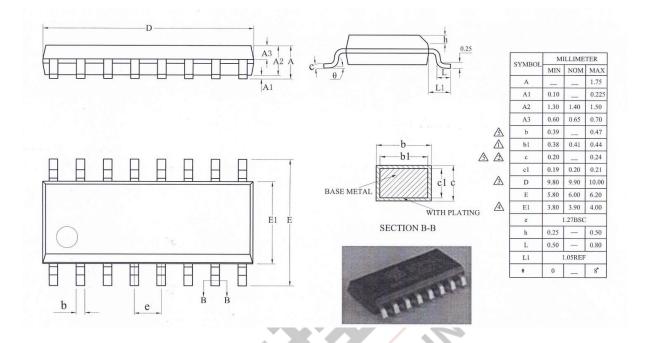
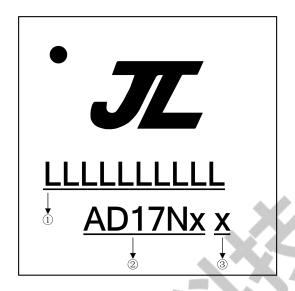


Figure 4-1 AD172A Package



5 IC Marking Information



- ① LLLLLLLLL: Production Batch
- ② AD17Nx: Chip Model
- 3 Built-in flash size
 - 0: No Flash Memory
 - 2: 2Mbit Flash
 - 4: 4Mbit Flash
 - 8: 8Mbit Flash
 - 6: 16Mbit Flash
 - 3: 32Mbit Flash



6 Solder-Reflow Condition

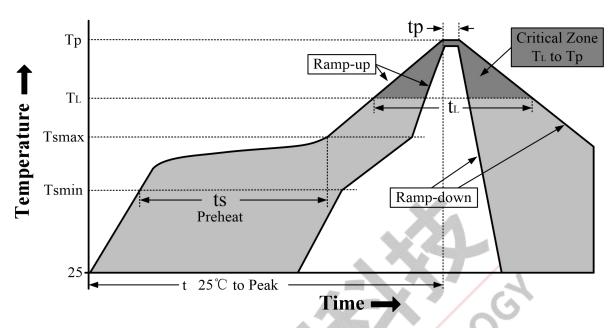


Figure 6-1 Classification Reflow Profile

Classification Profiles

Table 6-1

	Profile Feature	Sn-Pb Eutectic Assembly	Pb-Free Assembly	
	Temperature Min (T _{smin})	100 °C	150 ℃	
Preheat/	Temperature Max (T _{smax})	150 °C	200 ℃	
Soak	Time (ts) from (T _{smin} to T _{sma} x)	60-120 seconds	60-180 seconds	
Average ra	amp-up rate $(T_{smax} \text{ to } T_p)$	3 °C/second max	3 °C/second max	
Liquidous	temperature (T _L)	183 ℃	217 ℃	
Time (t _L) 1	maintained above T _L	60-150 seconds	60-150 seconds	
Peak pack	age body temperature (Tp)	See Table 6-2.	See Table 6-3.	
Time within 5°C of actual Peak Temperature (tp)		10-30 seconds	20-40 seconds	
Ramp-down rate (T _p to T _L)		6 °C/second max.	6 °C/second max.	
Time 25	C to peak temperature	6 minutes max.	8 minutes max.	

Note 1: All temperatures refer to topside of the package, measured on the package body surface.

Note 2: Time within 5° C of actual peak temperature (tp) specified for the reflow profiles is a "supplier" minimum and "user" maximum.

SnPb - Classification Temperature

Table 6-2

Package	Volume mm ³	Volume mm ³		
Thickness	< 350	≥ 350		
<2.5 mm	240 +0/-5 °C	225 +0/-5 °C		
≥ 2.5 mm	225 +0/-5 °C	225 +0/-5 °C		



Pb-free - Classification Temperature Table 6-3

Package	Volume mm ³	Volume mm ³	Volume mm ³
Thickness	< 350	350 - 2000	> 2000
< 1.6mm	260 ℃	260 ℃	260 °C
1.6 mm - 2.5mm	260 ℃	250 ℃	245 ℃
> 2.5mm	250 °C	245 ℃	245 ℃





7 Revision History

Date	Revision	Description
2023.07.13	V1.0	Initial Release.

